

EV317136337

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

**priority** Application Serial No. ....10/196,484  
**priority** Confirmation No. ....5768  
**priority** Filing Date .....July 15, 2002  
Inventor.....J. Mattson  
Assignee.....Micron Technology, Inc.  
**priority** Group Art Unit.....2818  
**priority** Examiner .....L.K. Tran  
Attorney's Docket No. ....MI22-2376  
Customer No. ....021567  
Title: Methods Of Forming Magnetoresistive Memory Devices

**PRELIMINARY AMENDMENT**

To: Mail Stop Patent Application  
Commissioner for Patents  
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**AMENDMENTS**